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Van der Waals heterostructure of graphene and germanane: tuning the ohmic contact by electrostatic gating and mechanical strain

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Correction for 'Van der Waals heterostructure of graphene and germanane: tuning the ohmic contact by electrostatic gating and mechanical strain' by A. Bafekry *et al.*, *Phys. Chem. Chem. Phys.*, 2021, DOI: 10.1039/D1CP03632G.

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The authors would like to correct addresses 'e' and 'f' in the affiliation list as these were incorrectly swapped in the published article. The corrected affiliations for this paper are as shown below.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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